

Gate Driver Providing Galvanic Isolation Series Isolation voltage 3750Vrms **1ch Gate Driver Providing Galvanic Isolation**

BM61S40RFV-C

General Description

The BM61S40RFV-C is a gate driver with an isolation voltage of 3750 Vrms, I/O delay time of 65ns, and minimum input pulse width of 60ns. It incorporates the Under-Voltage Lockout (UVLO) function, Miller clamp function and Over-Voltage Protect (OVP) function.

Features

- AEC-Q100 Qualified^(Note 1)
- Providing Galvanic Isolation
- Active Miller Clamping
- Under-Voltage Lockout Function
- Over-Voltage Protect Function
- UL1577 Recognized: File E356010 (Note 1) Grade1

Applications

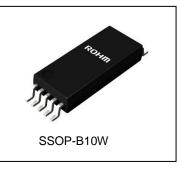
SiC MOSFET Gate Drive

Key Specifications

- Isolation Voltage: 3750 Vrms Maximum Gate Drive Voltage: 20 V I/O Delay Time: 65 ns(Max) Minimum Input Pulse Width: 60 ns 4 A
 - Output Current

Package SSOP-B10W

W(Typ) x D(Typ) x H(Max) 3.5 mm x10.2 mm x 1.9 mm



Typical Application Circuits

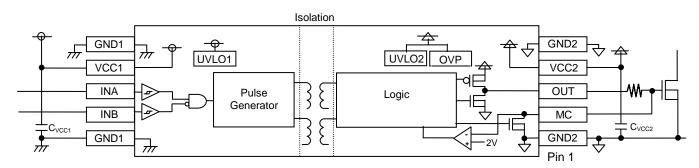


Figure 1. For Driving SiC MOSFET without Negative Power Supply

OProduct structure : Silicon integrated circuit OThis product has no designed protection against radioactive rays

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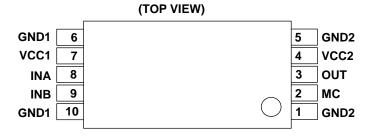
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Recommended Range of External Constants

Pin Name	Sumbol	Recor	Unit		
Pin Name	Symbol	Min	Тур	Max	Unit
VCC1	C _{VCC1}	0.1	1.0	-	μF
VCC2	C_{VCC2}	0.01	_(Note 2)	-	μF
(1)-(-0))/-/	un nonording to t	l			

(Note 2) Value according to the load

Pin Configurations



Pin Descriptions

Pin No.	Pin Name	Function
1	GND2	Output-side ground pin
2	MC	Miller clamp pin
3	OUT	Output pin
4	VCC2	Output-side power supply pin
5	GND2	Output-side ground pin
6	GND1	Input-side ground pin
7	VCC1	Input-side power supply pin
8	INA	Control input A pin
9	INB	Control input B pin
10	GND1	Input-side ground pin

Pin Descriptions - continued

1) VCC1 (Input-side Power Supply Pin) The VCC1 pin is a power supply pin on the input side. To suppress voltage fluctuations due to the current to drive internal transformers, connect a bypass capacitor between the VCC1 and the GND1 pins.

- 2) GND1 (Input-side Ground Pin) The GND1 pin is a ground pin on the input side.
- 3) VCC2 (Output-side Power Supply Pin) The VCC2 pin is a power supply pin on the output side. To reduce voltage fluctuations due to OUT pin output current, connect a bypass capacitor between the VCC2 and the GND2 pins.
- 4) GND2 (Output-side Ground Pin) The GND2 pin is a ground pin on the output side.
- 5) INA, INB (Control Input A/B Pin)

The INA and INB pins are used to determine output logic.

INB	INA	OUT
Н	L	L
Н	Н	L
L	L	L
L	Н	Н

6) OUT (Output Pin)

The OUT pin is used to drive the gate of a power device.

7) MC (Miller Clamp Pin)

The MC pin is for preventing the increase in gate voltage due to the Miller current of the power device connected to the OUT pin. If the Miller Clamp function is not used, short-circuit the MC pin to the GND2 pin.

Description of Functions and Examples of Constant Setting

1) Miller Clamp Function When the INA=L or INB=H and OUT pin voltage < V_{MCON} (typ 2V), the internal MOSFET of the MC pin is turned ON.

INA	INB	MC	Internal MOSFET of the MC Pin
L	х	Less Than V_{MCON}	ON
Х	н	Less Than V_{MCON}	ON
Н	L	Х	OFF

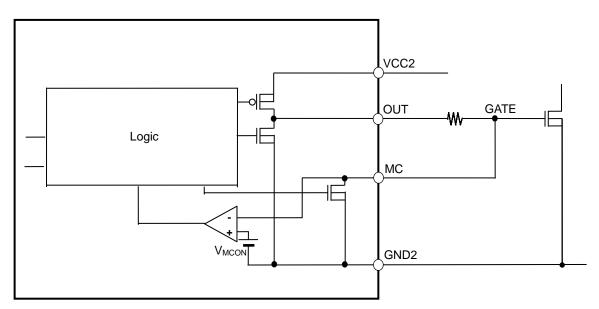
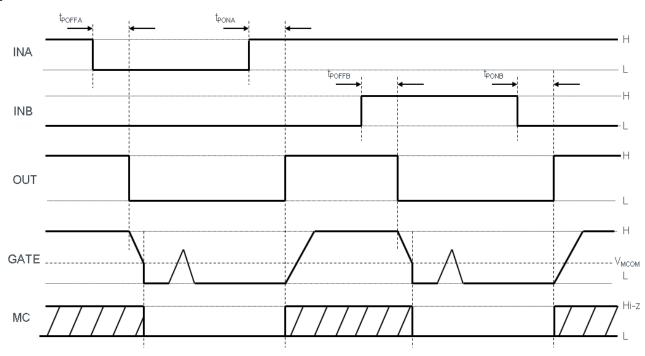
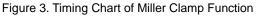


Figure 2. Block Diagram of Miller Clamp Function





Description of Functions and Examples of Constant Setting - continued

2) Under-Voltage Lockout (UVLO) Function

The BM61S40RFV-C incorporates the Under-Voltage Lockout (UVLO) function both on the Input-side and the output-side. When the power supply voltage drops to the UVLO ON voltage (input-side typ 4.0 V, output-side 14.5 V), the OUT pin will output the "L" signal. In addition, to prevent malfunctions due to noises, a mask time of $t_{\rm UVLO1MSK}$ (typ 1.5 µs) and $t_{\rm UVLO2MSK}$ (typ 2.9 µs) are set on both the input-side and the output-side. After the UVLO on Input-side is released, the input signal will take effect from the time after the input signal switches.

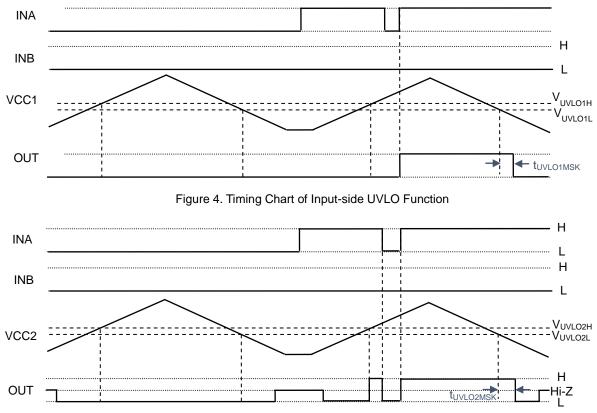
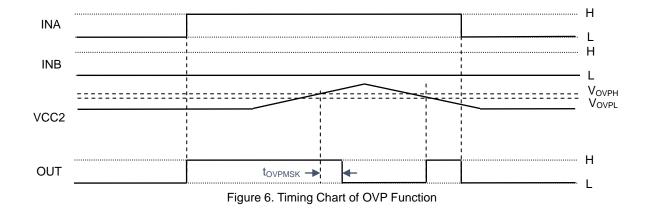


Figure 5. Timing Chart of Output-side UVLO Function

Description of Functions and Examples of Constant Setting - continued

3) Over-Voltage Protect (OVP) Function

The BM61S40RFV-C incorporates the Over-Voltage Protect (OVP) function on the output-side. When the power supply voltage exceeds the OVP ON voltage (typ 21.5 V), the OUT pin will output the "L" signal. In addition, to prevent malfunctions due to noises, a mask time of t_{OVPMSK} (typ 10 µs) is set. After the OVP is released, OUT pin becomes the logic according to the input logic



4) I/O Condition Table

			Output				
No.	Status	VCC1	VCC2	INB	INA	OUT	MC
1	VCC1 UVLO	UVLO	х	х	х	L	L
2	VCC2 UVLO	х	UVLO	х	х	L	L
3	VCC2 OVP	х	OVP	х	х	L	L
4	INB Active	No UVLO	No UVLO No OVP	н	х	L	L
5	Normal Operation L Input	No UVLO	No UVLO No OVP	L	L	L	L
6	Normal Operation H input	No UVLO	No UVLO No OVP	L	Н	Н	Hi-Z

X: Don't care

Absolute Maximum Ratings

Parameter	Symbol	Limits	Unit
Input-side Supply Voltage	V _{CC1}	-0.3 to +7.0 ^(Note 3)	V
Output-side Supply Voltage	V _{CC2}	-0.3 to +30.0 ^(Note 4)	V
INA Pin Input Voltage	VINA	-0.3 to +VCC1+0.3 or +7.0 ^(Note 3)	V
INB Pin Input Voltage	VINB	-0.3 to +VCC1+0.3 or +7.0 ^(Note 3)	V
OUT Pin Output Current (Peak 10µs)	I _{OUTPEAK}	self limited	A
Storage Temperature Range	Tstg	-55 to +150	°C
Maximum Junction Temperature	Tjmax	+150	°C

(Note 3) Relative to GND1.

(Note 4) Relative to GND2.

Caution 1: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Caution 2: Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB boards with thermal resistance taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.

Thermal Resistance (Note 5)

Deservator	Ourseland	Thermal Res	l la it	
Parameter	Symbol	1s ^(Note 7)	2s2p ^(Note 8)	Unit
SSOP-B10W				
Input-side Junction to Ambient	θ _{JA1}	172.1	101.8	°C/W
Output-side Junction to Ambient	θ _{JA2}	180.2	108.9	°C/W
Input-side Junction to Top Characterization Parameter ^(Note 6)	Ψ_{JT1}	32	27	°C/W
Output-side Junction to Top Characterization Parameter ^(Note 6)	Ψ_{JT2}	82	60	°C/W

(Note 5) Based on JESD51-2A (Still-Air)

(Note 6) The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package. (Note 7) Using a PCB board based on JESD51-3. (Note 8) Using a PCB board based on JESD51-7.

Layer Number of Measurement Board	Material	Board Size				
Single	FR-4	114.3 mm x 76.2 mm x 1.57 mmt				
Тор						
Copper Pattern	Thickness					
Footprints and Traces	70 µm					
		-				

Layer Number of Measurement Board	Material	Board Size			
4 Layers	FR-4	114.3 mm x 76.2 mm x 1.6 mmt			
Тор		2 Internal Layers		Bottom	
Copper Pattern	Thickness	Copper Pattern	Thickness	Copper Pattern	Thickness
Footprints and Traces	70 µm	74.2 mm x 74.2 mm	35 µm	74.2 mm x 74.2 mm	70 µm

Recommended Operating Ratings

Parameter	Symbol	Min	Max	Units
Input-side Supply Voltage	V _{CC1} ^(Note 9)	4.5	5.5	V
Output-side Supply Voltage	V _{CC2} ^(Note 10)	16	20	V
Operating Temperature	Topr	-40	125	°C

(Note 9) Relative to GND1. (Note 10) Relative to GND2.

Insulation Related Characteristics

Basic Insulation Requirements according to VDE0884-11(pending)

Parameter	Symbol	Characteristic	Units
Insulation Classification Per EN 60664-1, Table 1 For Rated Main Voltage< 150Vrms For Rated Main Voltage< 300Vrms For Rated Main Voltage< 450Vrms For Rated Main Voltage< 600Vrms		Rated Impulse Voltage I - IV I - IV I - III I - III	-
Climatic Classification		40/125/21	-
Pollution Decree(EN 60664-1)		2	-
Minimum External Clearance	CLR	8.1	mm
Minimum External Creepage	CPG	8.1	mm
Minimum Internal Gap (Internal Clearance)		0.012	mm
Minimum Comparative Tracking Index	CTI	>400	-
Minimum Repetitive Insulation Voltage	VIORM	891	
Input to Output Test Voltage, Method b VIORM * 1.875= VPR, Productive Test, tm = 1s, Partial Discharge < 5pC	V _{PR}	1671	V _{peak}
Surge Isolation Voltage	VIOSM	6000	
Highest Allowable Voltage, 1min	VIOTM	5300	
Insulation Resistance at T_s , VIO = 500V	R _{IO}	>10 ⁹	Ω

Recognized under UL 1577

Description	Symbol	Characteristic	Units
Insulation Withstand Voltage / 1min	V _{ISO}	3750	Vrms
Insulation Test Voltage / 1s	V _{ISO}	4500	Vrms

UL1577 Ratings Table Following values are described in UL Report.

Parameter	Values	Units	Conditions
Side 1 (Input Side) Circuit Current	0.4	mA	VCC1=5.0V, OUT=L
Side 2 (Output Side) Circuit Current	0.7	mA	VCC2=15V, OUT=L
Side 1 (Input Side) Consumption Power	2	mW	VCC1=5.0V, OUT=L
Side 2 (Output Side) Consumption Power	12.6	mW	VCC2=15V, OUT=L
Isolation Voltage	3750	Vrms	
Maximum Operating (Ambient) Temperature	125	°C	
Maximum Junction Temperature	150	°C	
Maximum Storage Temperature	150	°C	
Maximum Data Transmission Rate	8.33	MHz	

Electrical Characteristics

(Unless otherwise specified Ta=-40°C to +125°C, V_{CC1}=4.5V to 5.5V, V_{CC2}=16V to 20V)

(Unless otherwise specified Ta=-						a
Parameter	Symbol	Min	Тур	Max	Unit	Conditions
General Input-side Circuit Current 1		0.2	0.4	1.0	mA	INA=L,INB=H
Input-side Circuit Current 2	I _{CC11}	1.0	2.0	4.0	-	INA=100kHz, Duty=50%
	I _{CC12}				mA	
Output-side Circuit Current 1	I _{CC21}	0.30	0.70	1.20	mA	OUT=L
Output-side Circuit Current 2 Logic Block	I _{CC22}	0.22	0.52	0.90	mA	OUT=H
-	V	2.0		1/	V	
Logic High Level Input Voltage	Vinh	2.0	-	V _{CC1}	-	INA, INB
Logic Low Level Input Voltage	VINL	0	-	0.8	V	INA, INB
Logic Pull-down Resistance	RIND	25	50	100	kΩ	INA
Logic Pull-up Resistance	RINU	25	50	100	kΩ	INB
Logic Input Minimum Pulse Width	t _{INMIN}	60	-	-	ns	INA, INB
Output						
OUT ON Resistance (Source)	Ronh	0.3	0.67	1.5	Ω	I _{OUT} =-40mA
OUT ON Resistance (Sink)	R _{ONL}	0.15	0.45	0.98	Ω	I _{OUT} =40mA
OUT Maximum Current (Source)	I _{OUTMAXH}	4.0	-	-	А	VCC2=18 V, Guaranteed by Design
OUT Maximum Current (Sink)	IOUTMAXL	4.0	-	-	А	VCC2=18 V, Guaranteed by Design
	t _{PONA}	45	55	65	ns	INA=PWM, INB=L
Turn ON Time	t _{PONB}	45	55	65	ns	INA=H, INB=PWM
	t POFFA	45	55	65	ns	INA=PWM, INB=L
Turn OFF Time	t _{POFFB}	45	55	65	ns	INA=H, INB=PWM
	t _{PDISTA}	-10	0	+10	ns	t _{POFFA} — t _{PONA}
Propagation Distortion	t _{PDISTB}	-10	0	+10	ns	t _{POFFB} – t _{PONB}
Part to Part Skew	Tsk-pp	-	-	20	ns	
Rise Time	t _{RISE}		15		ns	2 nF between OUT-GND2
Fall Time			15	_	ns	2 nF between OUT-GND2
MC ON Resistance	t _{FALL}	0.15	0.45	0.98	Ω	I_{MC} =40 mA
					V	
MC ON Threshold Voltage	V _{MCON}	1.8	2	2.2	-	Cuaranteed by Design
Common Mode Transient Immunity	СМ	100	-	-	kV/μs	Guaranteed by Design
Protection Functions	1					
V _{CC1} UVLO OFF Voltage	V _{UVLO1H}	3.95	4.2	4.45	V	
V _{CC1} UVLO ON Voltage	V _{UVLO1L}	3.75	4.0	4.25	V	
V _{CC1} UVLO Mask Time	t _{UVLO1MSK}	0.4	1.5	5.0	μs	
V _{CC2} UVLO OFF Voltage	$V_{\rm UVLO2H}$	14.6	15.0	15.4	V	
V _{CC2} UVLO ON Voltage	V _{UVLO2L}	14.1	14.5	14.9	V	
V _{CC2} UVLO Mask Time	t _{UVLO2MSK}	1.0	2.9	5.0	μs	
V _{CC2} OVP OFF Voltage	V _{OVPL}	20.6	21.0	21.4	V	
V _{CC2} OVP ON Voltage	V _{OVPH}	21.1	21.5	21.9	V	
V _{CC2} OVP Mask Time	t _{OVPMSK}	3.0	10.0	20.0	μs	

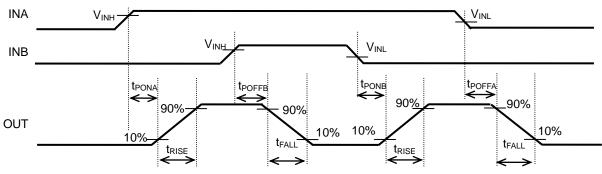
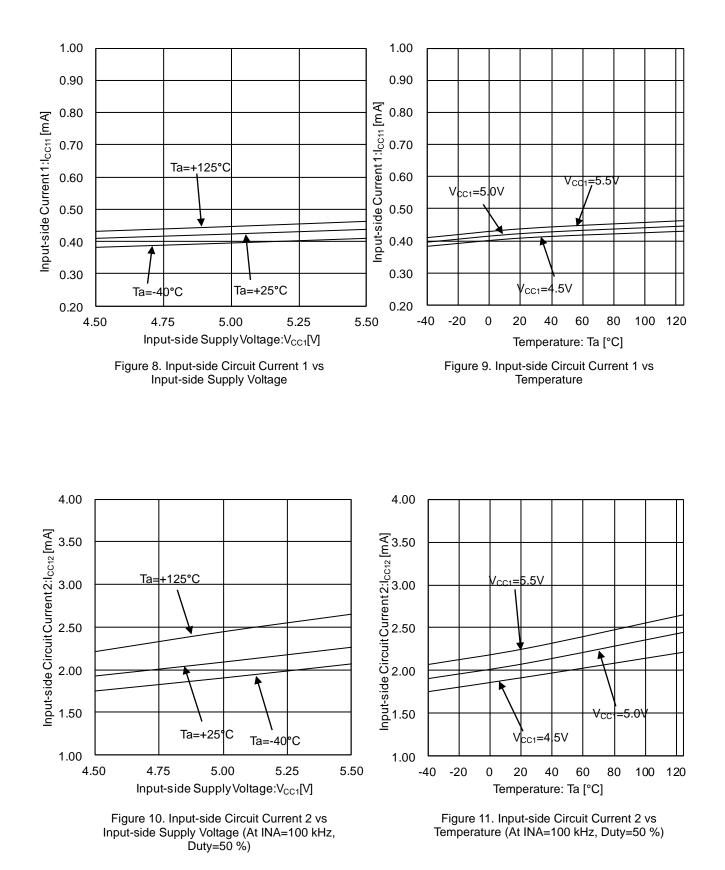
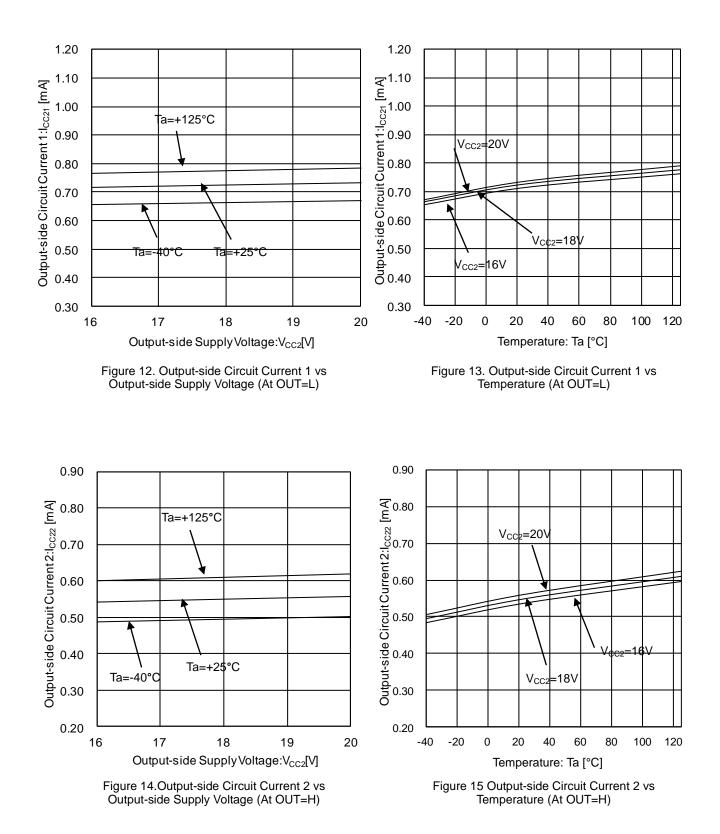
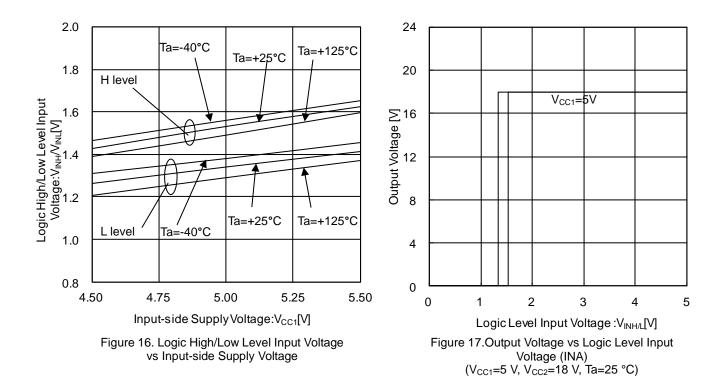


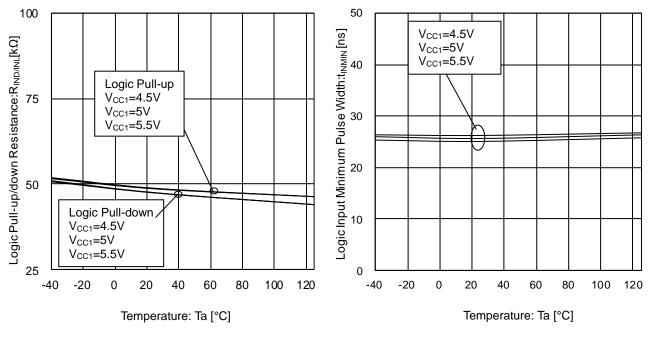
Figure 7. Timing Chart of IN-OUT

Typical Performance Curves









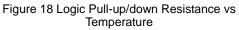
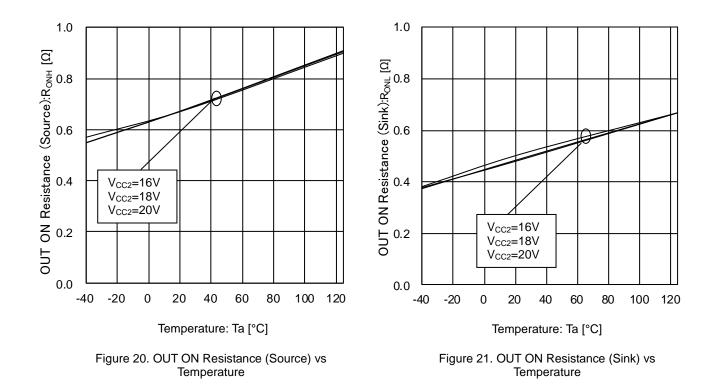
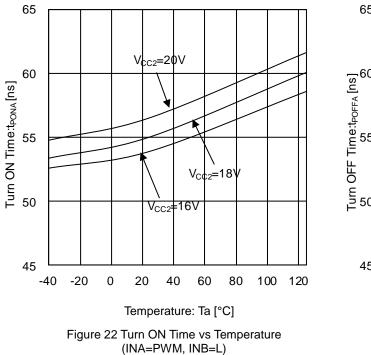
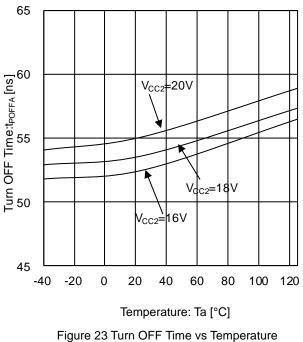
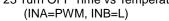


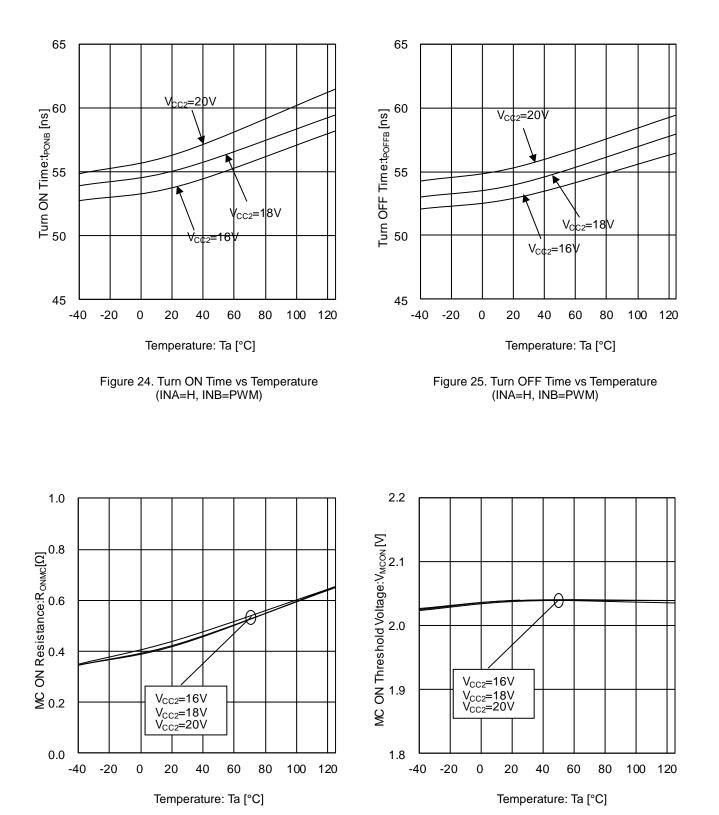
Figure 19 Logic Input Minimum Pulse Width vs Temperature

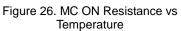


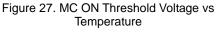


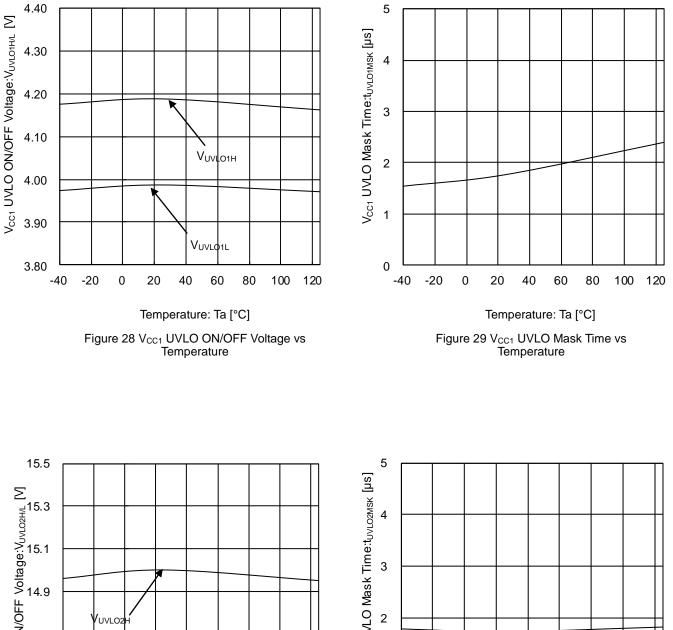


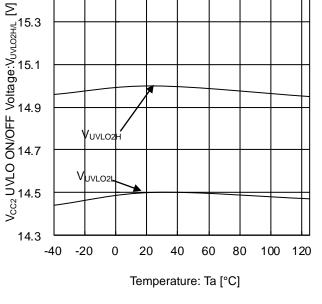


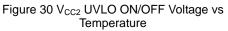


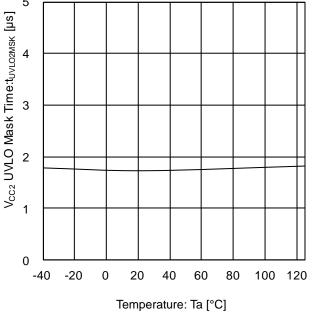


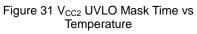


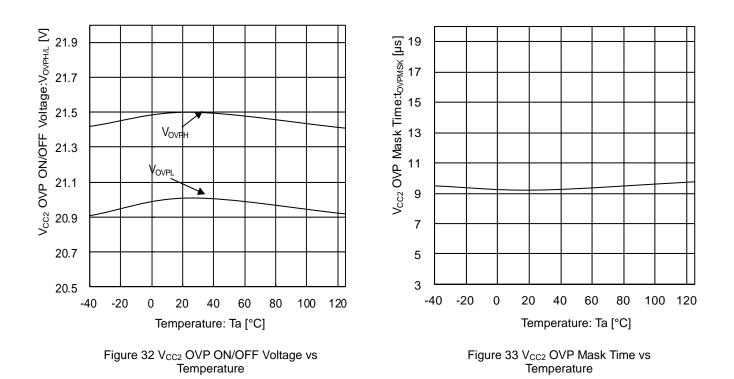












Selection of Components Externally Connected

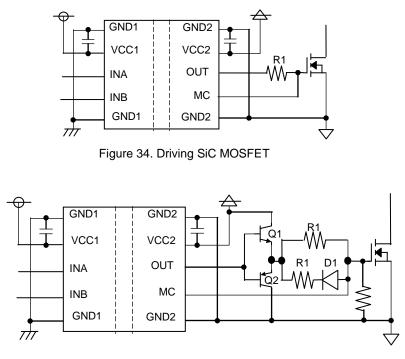


Figure 35. Driving SiC MOSFET with Buffer Circuit

Recommended Parts

	Manufacturer	Element	Part Number	
R1	ROHM	Resistor	LTR18EZP,LTR50UZP	
Q1	ROHM	NPN Transistor	2SCR542PFRA	
Q2	ROHM	PNP Transistor	2SAR542PFRA	
D1	ROHM	Diode	RBR3MM30ATF,RBR5LAM30ATF	

I/O Equivalence Circuits

Pin No.	Name				
FIII NO.	Function	I/O Equivalence Circuits			
1	OUT				
	Output Pin				
2	MC				
	Miller Clamp pin				
3 -	INA				
	Control Input pin A				
4	INB				
	Control Input pin B				

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Recommended Operating Conditions

The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

6. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

7. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

8. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

9. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

Operational Notes – continued

10. Unused Input Pins

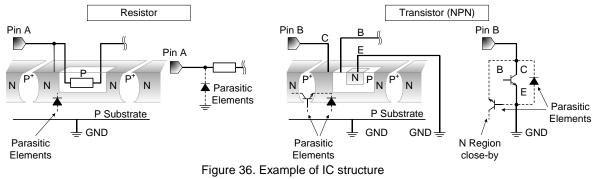
Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

11. Regarding the Input Pin of the IC

This IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

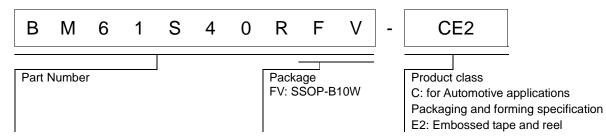
Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.



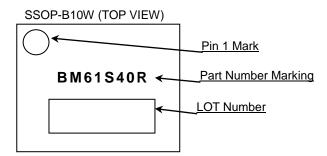
12. Ceramic Capacitor

When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

Ordering Information



Marking Diagram



Physical Dimension and Packing Information

Package Name SSOP-B10W 3.5 ± 0.2 MAX3. 85 (Include BURR) $5^{\circ} \pm 5^{\circ}$ 10 6 ŝ 2 $2\pm 0.$ 0±0. 10. ø. 2 15 1 ± 0 . 5±0. Ξ. 0. F F Γ 1 1 P I N MARK 0. $22^{+0.05}_{-0.03}$ 0.45 S 80 1. 9MAX 7±0. ÷ 0 8 1 ± 0 . (UNIT:mm) 0. 08 S PKG:SSOP-B10W 0. $24 \frac{+0.05}{-0.04} \oplus 0.08 \text{ }$ 0 0.65 Drawing No. EX078-5002 < Tape and Reel Information > Embossed carrier tape (with dry pack) Таре Quantity 1500pcs Direction of feed E2 The direction is the pin 1 of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand 0 Ο Ο Ο Ο Ο Ο Ο Ο 0 Ο Ο

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E2 TR

TL E1

E2 TR

TL E1

Reel

E2 TR

Pocket Quadrants

TL E1

E2 TR

TL E1

E2 TR

TL E1

E2 TR

TL E1

Direction of feed

Revision History

Date	Revision	Changes
14.May.2018	001	New Release
30.Mar.2020	002	$\begin{array}{llllllllllllllllllllllllllllllllllll$

Notice

Precaution on using ROHM Products

 If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), aircraft/spacecraft, nuclear power controllers, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

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CLASSII	CLASSⅢ	CLASS II b		
CLASSⅣ	CLASSI	CLASSII	CLASSⅢ	

2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:

[a] Installation of protection circuits or other protective devices to improve system safety

[b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure

- 3. Our Products are not designed under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
 - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

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